## 2008 ANNA UNIVERSITY B.E ELECTRICAL AND ELECTRONICS ENGINEERING

ELECTRONICS DEVICE

TIME: 3 HOUR MARK: 100

Nercon

## Answer ALL questions.

## PAR T A - (5×4=20 marks)

1.What is diffusion current?

2.State early effect.

3.Why FET called unipolar device?

4.What is photodiode?

5.What is charge couple device?

## Part B - (5\*16=80 marks)

1.Define and explain zener diode briefly.

2.Write detail note on

LED and phototransistor.

3.Explain construction and characteristics of JFET.

4.Write a detail note on transistor characteristics.

5.Briefly explain diffusion capacitance.

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